Low Capacitance TSOP-6 Diode-TVS Array for High Speed Data Lines Protection

The NUP4201MR6 transient voltage suppressor is designed to protect high speed data lines from ESD, EFT, and lighting.

Features:

- Low Capacitance (3 pF Maximum Between I/O Lines)
- ESD Rating of Class 3B (Exceeding 8 kV) per Human Body model and Class C (Exceeding 400 V) per Machine Model
- Protection for the Following IEC Standards: IEC 61000-4-2 (ESD) 15 kV (air) 8 kV (contact) IEC 61000-4-4 (EFT) 40 A (5/50 ns) IEC 61000-4-5 (lighting) 23 A (8/20 μs)
- UL Flammability Rating of 94 V–0

Typical Applications:

- High Speed Communication Line Protection
- USB 1.1 and 2.0 Power and Data Line Protection
- Digital Video Interface (DVI)
- Monitors and Flat Panel Displays

MAXIMUM RATINGS (T_J = 25° C unless otherwise noted)

Rating	Symbol	Value	Unit	
Peak Power Dissipation 8 x 20 μ S @ T _A = 25°C (Note 1)	P _{pk}	500	W	
Operating Junction Temperature Range	TJ	-40 to +125	°C	
Storage Temperature Range	T _{stg}	-55 to +150	°C	
Lead Solder Temperature – Maximum (10 Seconds)	ΤL	235	°C	
Human Body Model (HBM) Machine Model (MM) IEC 61000–4–2 Air (ESD) IEC 61000–4–2 Contact (ESD)	ESD	16000 400 20000 20000	V	

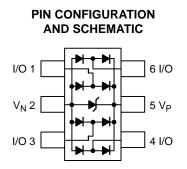
1. Non-repetitive current pulse per Figure 1 (Pin 5 to Pin 2)



ON Semiconductor®

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TSOP-6 LOW CAPACITANCE DIODE TVS ARRAY 500 WATTS PEAK POWER 6 VOLTS





TSOP-6 CASE 318G PLASTIC

MARKING DIAGRAM



63 = Specific Device Code ^M = Date Code

ORDERING INFORMATION

Device	Package	Shipping		
NUP4201MR6T1	TSOP-6	3000/Tape & Reel		

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Reverse Working Voltage	V _{RWM}	(Note 2)			5.0	V
Breakdown Voltage	V _{BR}	I _T =1 mA, (Note 3)	6.0			V
Reverse Leakage Current	I _R	V _{RWM} = 5 V			5.0	μΑ
Clamping Voltage	V _C	I _{PP} = 5 A (Note 4)			12.5	V
Clamping Voltage	V _C	I _{PP} = 8 A (Note 4)			20	V
Maximum Peak Pulse Current	I _{PP}	8x20 μs Waveform			25	А
Junction Capacitance	CJ	$V_R = 0 V$, f=1 MHz between I/O Pins and GND		3.0	5.0	pF
Junction Capacitance	CJ	V _R = 0 V, f=1 MHz between I/O Pins		1.5	3.0	pF

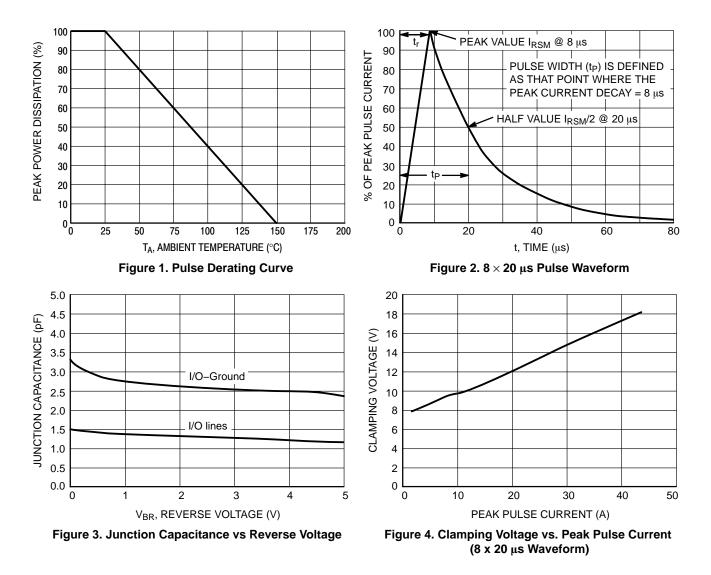
2. TVS devices are normally selected according to the working peak reverse voltage (V_{RWM}), which should be equal or greater than the DC or continuous peak operating voltage level.

3. V_{BR} is measured at pulse test current I_T.

4. Non-repetitive current pulse per Figure 1 (Pin 5 to Pin 2)

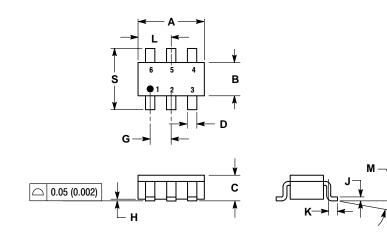


 $(T_J = 25^{\circ}C \text{ unless otherwise noted})$



PACKAGE DIMENSIONS

TSOP-6 CASE 318G-02 **ISSUE J**



NOTES:
DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
CONTROLLING DIMENSION: MILLIMETER.
MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

	MILLIMETERS		INCHES		
DIM	MIN	MAX	MIN	MAX	
Α	2.90	3.10	0.1142	0.1220	
В	1.30	1.70	0.0512	0.0669	
С	0.90	1.10	0.0354	0.0433	
D	0.25	0.50	0.0098	0.0197	
G	0.85	1.05	0.0335	0.0413	
Н	0.013	0.100	0.0005	0.0040	
J	0.10	0.26	0.0040	0.0102	
ĸ	0.20	0.60	0.0079	0.0236	
L	1.25	1.55	0.0493	0.0610	
М	0	10	0	10	
S	2.50	3.00	0.0985	0.1181	

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